

# Features

- Any frequency between 1 MHz and 220 MHz accurate to 6 decimal places
- LVPECL and LVDS output signaling types
- 0.6ps RMS phase jitter (random) over 12 kHz to 20 MHz bandwidth
- Frequency stability as low as ±5 ppm. Contact SiTime for tighter stability options
- Industrial and extended commercial temperature ranges
- Industry-standard packages: 3.2 x 2.5, 5.0 x 3.2 and 7.0 x 5.0 mm
- For frequencies higher than 220 MHz, refer to SiT5022 datasheet

## Applications

- SATA, SAS, 10GB Ethernet, Fibre Channel, PCI-Express
- Networking, broadband, instrumentation



| Electrical Characteristics                |                   |                    |                |                    |             |  |  |
|---|-------------------|--------------------|----------------|--------------------|-------------|--|--|
| Parameter and Conditions                  | Symbol            | Min.               | Тур.           | Max.               | Unit        | Condition  |  |
|   | L                 | VPECL an           | d LVDS, C      | ommon E            | lectrical C | haracteristics   |  |
| Supply Voltage                            | Vdd               | 2.97               | 3.3            | 3.63               | V           |  |  |
|   |                   | 2.25               | 2.5            | 2.75               | V           |  |  |
|   |                   | 2.25               | -              | 3.63               | V           | Termination schemes in Figures 1 and 2 - XX ordering code  |  |
| Output Frequency Range                    | f                 | 1                  | -              | 220                | MHz         |  |  |
| Initial Tolerance                         | F_init            | -2                 | -              | 2                  | ppm         | At 25°C after two reflows  |  |
| Stability Over Temperature                | F_stab            |                    |                |                    |             | Over operating temperature range at rated nominal power  |  |
|   |                   | -5                 | -              | +5                 | ppm         | supply voltage and load.   |  |
| <b>A A A B</b>                            |                   |                    |                |                    |             | Contact SiTime for tighter stability options.  |  |
| Supply Voltage                            | F_vdd             | -                  | 50             | -                  | ppb         | ±10% Vdd   |  |
| Output Load                               | F_load            | -2.5               | 0.1            | -                  | ppm         | 15 pF ±10% of load<br>25°C   |  |
| First Year Aging                          | F_aging1          |                    | _              | +2.5               | ppm         |  |  |
| 10-year Aging                             | F_aging10         | -5<br>-40          | _              | +5<br>+85          | °C          | 25°C<br>Industrial   |  |
| Operating Temperature Range               | T_use             | -40                | -              | +05                | °C          | Extended Commercial  |  |
| Pull Range                                | PR                |                    |                | -                  | -           |  |  |
| Upper Control Voltage                     | VC_U              | ±<br>Vdd-0.1       | 12.0, ±20, ±0  |                    | ppm<br>V    | All Vdds. Voltage at which maximum deviation is guaranteed.                                      |  |
| Control Voltage Range                     | VC_U<br>VC L      | -                  | _              | 0.1                | V           | All vuus. voltage at which maximum deviation is guaranteed.                                      |  |
| Control Voltage Input Impedance           | Z vc              | 100                |                | 0.1                | kΩ          |  |  |
| Frequency Change Polarity                 |                   |                    | Positive slope |                    | -           |  |  |
| Control Voltage -3dB Bandwidth            | V BW              | -                  | -              | 8                  | kHz         |  |  |
| Input Voltage High                        | VIH               | 70%                | _              | _                  | Vdd         | Pin 1, OE or ST  |  |
| Input Voltage Low                         | VIL               | _                  | _              | 30%                | Vdd         | Pin 1, OE or ST  |  |
| Input Pull-up Impedance                   | Zin               | _                  | 100            | 250                | kΩ          | Pin 1, OE logic high or logic low, or ST logic high  |  |
| input i un-up impedance                   | ۰۰۰ ۲_۰۰          | 2                  | -              | 200                | MΩ          | Pin 1, ST logic low  |  |
| Start un Tima                             | T atart           | -                  | 6              | 10                 |             | Measured from the time Vdd reaches its rated minimum value.                                      |  |
| Start-up Time                             | T_start           |                    | 6              | 10                 | ms          |  |  |
| Resume Time                               | T_resume          | -                  | 0              | -                  | ms          | In Standby mode, measured from the time ST pin crosses   |  |
| Duty Cycle                                | DC                | 45                 |                | 55                 | %           | Contact SiTime for tighter duty cycle  |  |
|   |                   | L                  |                | and AC C           |             |  |  |
| Current Consumption                       | Idd               | -                  | 61             | 69                 | mA          | Excluding Load Termination Current, Vdd = 3.3V or 2.5V   |  |
| OE Disable Supply Current                 | I_OE              | -                  | -              | 35                 | mA          | OE = Low<br>OE = Low   |  |
| Output Disable Leakage Current            | I_leak            | -                  | _              | 1<br>100           | μΑ          |  |  |
| Standby Current                           | I_std             | -                  | _              |                    | μA          | ST = Low, for all Vdds   |  |
| Maximum Output Current                    | I_driver<br>VOH   | -<br>Vdd-1.1       | -              | 30<br>Vdd-0.7      | mA<br>V     | Maximum average current drawn from OUT+ or OUT-<br>See Figure 1(a)                               |  |
| Output High Voltage<br>Output Low Voltage | VOH               | Vdd-1.1<br>Vdd-1.9 | _              | Vdd-0.7<br>Vdd-1.5 | V           | See Figure 1(a)  |  |
| Output Differential Voltage Swing         | VOL<br>V Swing    | 1.2                | - 1.6          | 2.0                | V           | See Figure 1(b)  |  |
| Rise/Fall Time                            | v_Swing<br>Tr, Tf | -                  | 300            | 2.0<br>500         | v<br>ps     | 20% to 80%, see Figure 1(a)  |  |
| OE Enable/Disable Time                    | T_oe              | _                  |                | 115                | ps<br>ns    | $f = 212.5 \text{ MHz} - \text{For other frequencies}, T_oe = 100 \text{ ns} + 3 \text{ period}$ |  |
| RMS Period Jitter                         | _                 | _                  | 1.2            | 1.7                | -           | f = 100  MHz, VDD = 3.3V or 2.5V   |  |
|   | T_jitt            |                    | 1.2            | 1.7                | ps          | f = 156.25 MHz, VDD = 3.3V or 2.5V   |  |
|   |                   | _                  | 1.2            | 1.7                | ps          | f = 212.5 MHz, VDD = 3.3V or 2.5V  |  |
| RMS Phase Jitter (random)                 | T_phj             | _                  | 0.6            | 0.85               | ps<br>ps    | f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz, all                                    |  |
|   | נייץ_י            | -                  | 0.0            | 0.00               | ha          | Vdds   |  |

# **Electrical Characteristics**



# Electrical Characteristics (continued)

| Parameter and Conditions       | Symbol | Min.  | Тур.     | Max.      | Unit       | Condition  |  |  |  |  |
|--------------------------------|--------|-------|----------|-----------|------------|--|--|--|--|--|
|                                |        | I     | LVDS, DC | and AC Cl | naracteris | tics   |  |  |  |  |
| Current Consumption            | ldd    | -     | 47       | 55        | mA         | Excluding Load Termination Current, Vdd = 3.3V or 2.5V             |  |  |  |  |
| OE Disable Supply Current      | I_OE   | -     | -        | 35        | mA         | OE = Low   |  |  |  |  |
| Differential Output Voltage    | VOD    | 250   | 350      | 450       | mV         | See Figure 2   |  |  |  |  |
| Output Disable Leakage Current | l_leak | -     | -        | 1         | μA         | OE = Low   |  |  |  |  |
| Standby Current                | I_std  | -     | -        | 100       | μA         | ST = Low, for all Vdds   |  |  |  |  |
| VOD Magnitude Change           | ΔVOD   | -     | -        | 50        | mV         | See Figure 2   |  |  |  |  |
| Offset Voltage                 | VOS    | 1.125 | 1.2      | 1.375     | V          | See Figure 2   |  |  |  |  |
| VOS Magnitude Change           | ΔVOS   | -     | -        | 50        | mV         | See Figure 2   |  |  |  |  |
| Rise/Fall Time                 | Tr, Tf | -     | 495      | 600       | ps         | 20% to 80%, see Figure 2   |  |  |  |  |
| OE Enable/Disable Time         | T_oe   | -     | -        | 115       | ns         | f = 212.5 MHz - For other frequencies, T_oe = 100ns + 3 period     |  |  |  |  |
| RMS Period Jitter              | T_jitt | -     | 1.2      | 1.7       | ps         | f = 100 MHz, VDD = 3.3V or 2.5V                                    |  |  |  |  |
|                                |        | -     | 1.2      | 1.7       | ps         | f = 156.25 MHz, VDD = 3.3V or 2.5V                                 |  |  |  |  |
|                                |        | -     | 1.2      | 1.7       | ps         | f = 212.5 MHz, VDD = 3.3V or 2.5V                                  |  |  |  |  |
| RMS Phase Jitter (random)      | T_phj  | -     | 0.6      | 0.85      | ps         | f = 156.25 MHz, Integration bandwidth = 12 kHz to 20 MHz, all Vdds |  |  |  |  |

# **Pin Description**

| Pin | Мар      |               | Functionality   |                  |
|-----|----------|---------------|---|------------------|
|     |          | V Control     | Voltage control   |                  |
| 1   | VC/OE/ST | Output Enable | H or Open: specified frequency output<br>L: output is high impedance                                    | Top View         |
|     |          | Standby       | H or Open: specified frequency output<br>L: Device goes to sleep mode. Supply current reduces to I_std. | VC/OE/ST 1 6 VDD |
| 2   | NC       | NA            | No Connect; Leave it floating or connect to GND for better heat dissipation                             | NC 2 5 OUT-      |
| 3   | GND      | Power         | VDD Power Supply Ground   | NC 2 5 OUT-      |
| 4   | OUT+     | Output        | Oscillator output   | GND 3 4 OUT+     |
| 5   | OUT-     | Output        | Complementary oscillator output   | GND 3 4 OUT+     |
| 6   | VDD      | Power         | Power supply voltage  |                  |

# **Absolute Maximum**

Attempted operation outside the absolute maximum ratings may cause permanent damage to the part. Actual performance of the IC is only guaranteed within the operational specifications, not at absolute maximum ratings.

| Parameter  | Min. | Max. | Unit |
|--|------|------|------|
| Storage Temperature  | -65  | 150  | °C   |
| VDD  | -0.5 | 4    | V    |
| Electrostatic Discharge (HBM)  | -    | 2000 | V    |
| Soldering Temperature (follow standard Pb free soldering guidelines) | -    | 260  | °C   |

# **Thermal Consideration**

| Package     | θJA, 4 Layer Board<br>(°C/W) | θJC, Bottom<br>(°C/W) |
|-------------|------------------------------|-----------------------|
| 7050, 6-pin | 142                          | 27                    |
| 5032, 6-pin | 97                           | 20                    |
| 3225, 6-pin | 109                          | 20                    |

# **Environmental Compliance**

| Parameter                  | Condition/Test Method     |  |  |
|----------------------------|---------------------------|--|--|
| Mechanical Shock           | MIL-STD-883F, Method 2002 |  |  |
| Mechanical Vibration       | MIL-STD-883F, Method 2007 |  |  |
| Temperature Cycle          | JESD22, Method A104       |  |  |
| Solderability              | MIL-STD-883F, Method 2003 |  |  |
| Moisture Sensitivity Level | MSL1 @ 260°C              |  |  |



# Waveform Diagrams

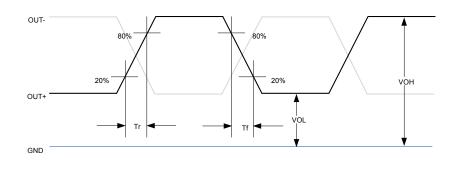


Figure 1(a). LVPECL Voltage Levels per Differential Pin (OUT+/OUT-)

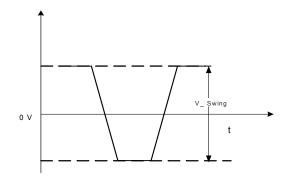


Figure 1(b). LVPECL Voltage Levels Across Differential Pair

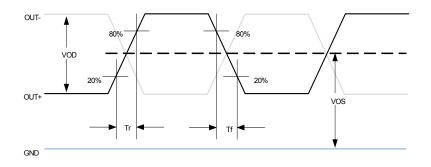


Figure 2. LVDS Voltage Levels per Differential Pin (OUT+/OUT-)



# **Termination Diagrams**

## LVPECL:

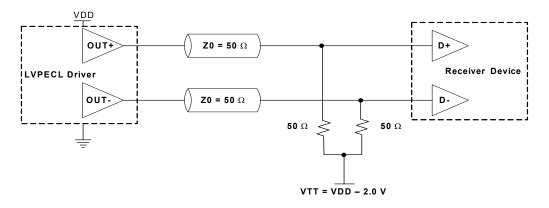


Figure 3. LVPECL Typical Termination

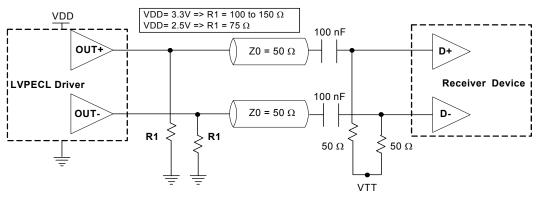


Figure 4. LVPECL AC Coupled Termination

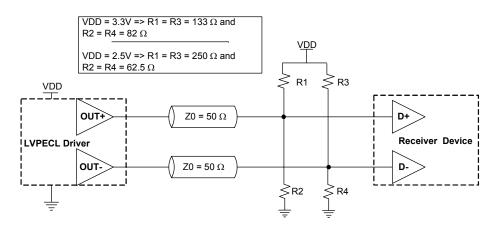


Figure 5. LVPECL with Thevenin Typical Termination



LVDS:

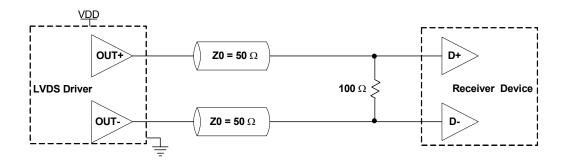
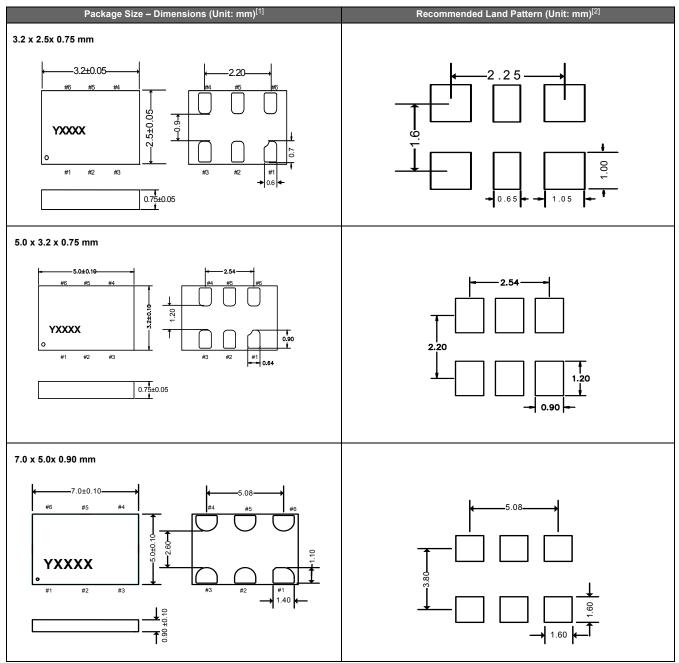


Figure 6. LVDS Single Termination (Load Terminated)



# **Dimensions and Patterns**



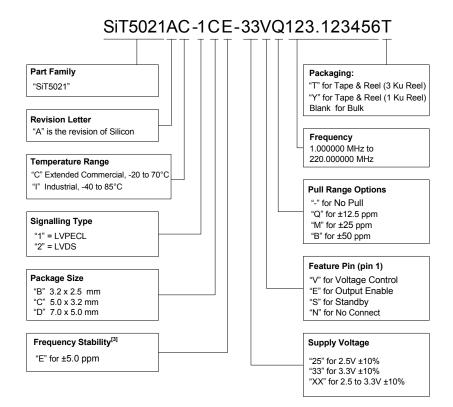
### Notes:

1. Top Marking: Y denotes manufacturing origin and XXXX denotes manufacturing lot number. The value of "Y" will depend on the assembly location of the device.

2. A capacitor of value 0.1  $\mu\text{F}$  between Vdd and GND is recommended.



# **Ordering Information**



### Note:

3. Contact SiTime for tighter stability options.

# **Ordering Codes for Supported Tape & Reel Packing Method**

| Device Size  | 12 mm T&R (3ku) | 12 mm T&R (1ku) | 12 mm T&R (250u) | 16 mm T&R (3ku) | 16 mm T&R (1ku) | 16 mm T&R (250u) |
|--------------|-----------------|-----------------|------------------|-----------------|-----------------|------------------|
| 7.0 x 5.0 mm | -               | -               | -                | Ţ               | Y               | Х                |
| 5.0 x 3.2 mm | Т               | Y               | Х                | -               | -               | -                |
| 3.2 x 2.5 mm | Т               | Y               | Х                | -               | -               | -                |

# **Frequencies Not Supported**

Range 1: From 209.000001 MHz to 210.999999 MHz



## **Revision History**

| Version | Release Date | Change Summary   |
|---------|--------------|--|
| 1.2     | 8/20/13      | Original   |
| 1.3     | 12/16/13     | Added input specifications, LVPECL/LVDS waveforms, packaging T&R options   |
| 1.4     | 12/11/14     | Modified Thermal Consideration values and Pin Configuration table (pin 1) and drawing  |
| 1.5     | 11/12/15     | <ul> <li>Revised stability over temperature and first year aging values in the electrical characteristics table</li> <li>Revised frequency stability and supply voltage options</li> </ul> |

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# **Supplemental Information**

The Supplemental Information section is not part of the datasheet and is for informational purposes only.



# Silicon MEMS Outperforms Quartz

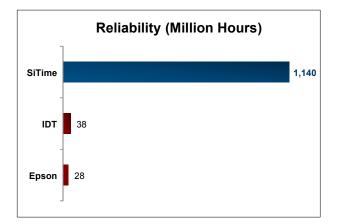


### **Best Reliability**

Silicon is inherently more reliable than quartz. Unlike quartz suppliers, SiTime has in-house MEMS and analog CMOS expertise, which allows SiTime to develop the most reliable products. Figure 1 shows a comparison with quartz technology.

### Why is SiTime Best in Class:

- SiTime's MEMS resonators are vacuum sealed using an advanced EpiSeal<sup>™</sup> process, which eliminates foreign particles and improves long term aging and reliability
- · World-class MEMS and CMOS design expertise





## Best Aging

Unlike quartz, MEMS oscillators have excellent long term aging performance which is why every new SiTime product specifies 10-year aging. A comparison is shown in Figure 2.

### Why is SiTime Best in Class:

- SiTime's MEMS resonators are vacuum sealed using an advanced EpiSeal process, which eliminates foreign particles and improves long term aging and reliability
- Inherently better immunity of electrostatically driven MEMS resonator

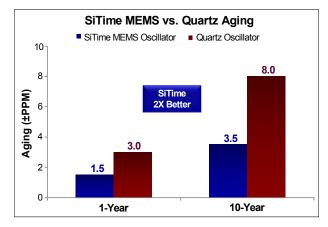


Figure 2. Aging Comparison<sup>[2]</sup>

## Best Electro Magnetic Susceptibility (EMS)

SiTime's oscillators in plastic packages are up to 54 times more immune to external electromagnetic fields than quartz oscillators as shown in Figure 3.

### Why is SiTime Best in Class:

- Internal differential architecture for best common mode noise rejection
- Electrostatically driven MEMS resonator is more immune to EMS

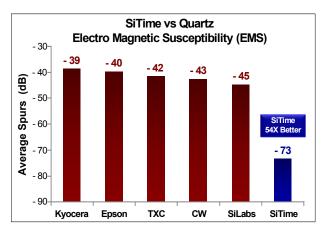


Figure 3. Electro Magnetic Susceptibility (EMS)<sup>[3]</sup>

## **Best Power Supply Noise Rejection**

SiTime's MEMS oscillators are more resilient against noise on the power supply. A comparison is shown in Figure 4.

### Why is SiTime Best in Class:

- On-chip regulators and internal differential architecture for common mode noise rejection
- · Best analog CMOS design expertise

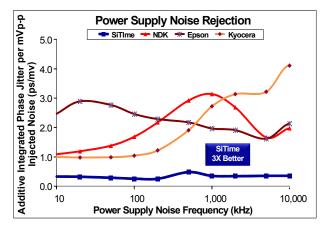


Figure 4. Power Supply Noise Rejection<sup>[4]</sup>



### **Best Vibration Robustness**

High-vibration environments are all around us. All electronics, from handheld devices to enterprise servers and storage systems are subject to vibration. Figure 5 shows a comparison of vibration robustness.

### Why is SiTime Best in Class:

- The moving mass of SiTime's MEMS resonators is up to 3000 times smaller than quartz
- Center-anchored MEMS resonator is the most robust design

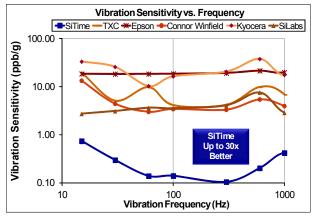


Figure 5. Vibration Robustness<sup>[5]</sup>

### Notes:

- 1. Data Source: Reliability documents of named companies.
- 2. Data source: SiTime and quartz oscillator devices datasheets.
- 3. Test conditions for Electro Magnetic Susceptibility (EMS):
  - According to IEC EN61000-4.3 (Electromagnetic compatibility standard)
     Field strength: 20/m
  - Field strength: 3V/m
  - Radiated signal modulation: AM 1 kHz at 80% depth
  - Carrier frequency scan: 80 MHz 1 GHz in 1% steps
  - Antenna polarization: Vertical
  - · DUT position: Center aligned to antenna

### Devices used in this test:

SiTime, SiT9120AC-1D2-33E156.250000 - MEMS based - 156.25 MHz Epson, EG-2102CA 156.2500M-PHPAL3 - SAW based - 156.25 MHz TXC, BB-156.250MBE-T - 3rd Overtone quartz based - 156.25 MHz Kyocera, KC7050T156.250P30E00 - SAW based - 156.25 MHz Connor Winfield (CW), P123-156.25M - 3rd overtone quartz based - 156.25 MHz SiLabs, Si590AB-BDG - 3rd overtone quartz based - 156.25 MHz

### 4. 50 mV pk-pk Sinusoidal voltage.

Devices used in this test:

SiTime, SiT8208AI-33-33E-25.000000, MEMS based - 25 MHz NDK, NZ2523SB-25.6M - quartz based - 25.6 MHz Kyocera, KC2016B25M0C1GE00 - quartz based - 25 MHz Epson, SG-310SCF-25M0-MB3 - guartz based - 25 MHz

- 5. Devices used in this test: same as EMS test stated in Note 3.
- 6. Test conditions for shock test:
- MIL-STD-883F Method 2002
- Condition A: half sine wave shock pulse, 500-g, 1ms
- Continuous frequency measurement in 100 µs gate time for 10 seconds
- Devices used in this test: same as EMS test stated in Note 3

7. Additional data, including setup and detailed results, is available upon request to qualified customers. Please contact productsupport@sitime.com.

# Best Shock Robustness

SiTime's oscillators can withstand at least 50,000 g shock. They all maintain their electrical performance in operation during shock events. A comparison with quartz devices is shown in Figure 6.

### Why is SiTime Best in Class:

- The moving mass of SiTime's MEMS resonators is up to 3000 times smaller than quartz
- Center-anchored MEMS resonator is the most robust design

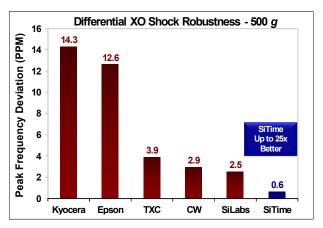


Figure 6. Shock Robustness<sup>[6]</sup>

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- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



### Как с нами связаться

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